Photocatalytic and Optical Performances of CeO$_2$ by Substitution of Titanium

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In this contribution, density functional theory-based calculations were carried out to assess the electronic, photocatalytic and optical properties of Ce$_{1-x}$Ti$_x$O$_2$ system. Ti incorporation resulted in a decrease in Ce 4f states and an increase in Ti 3d states in the bottom of conduction band. Furthermore, it was found that doping ceria with Ti-like transition metals could evidently shift the absorption of pure CeO$_2$ towards the higher wavelength range. These findings can provide some new insights for designing CeO$_2$-based photocatalysts with high photocatalytic performance. To the best of our knowledge, this investigation calculates the Mullikan charge transfer of Ce$_{1-x}$Ti$_x$O$_2$ system for the first time. Charge transfer reveals an ionic bond between Ce or Ti and O, and covalent bonds between Ce and Ti atoms in the studied systems.

Keywords: Rare earth oxides (REOs), Cerium oxide (CeO$_2$), Computational modeling, Density functional theory (DFT), Density of states (DOSs), Ti-doping

INTRODUCTION

Over the past decades, a great deal of research has been concentrated on rare-earth oxides (REOs) [1,2]. Their partially filled 4f and 5d orbitals cause high electrical conductivity and thermal stability [3]. Cerium (Ce) has unusual characteristics linked to the presence of only one 4f electron in addition to the 5d filled state. Cerium oxide (CeO$_2$) containing materials have been gaining great scientific interest due to demonstrating a number of extraordinary properties which directly depend on the presence of point defects; i.e., oxygen vacancies generated due to reducing Ce$^{4+}$ to Ce$^{3+}$ oxidation state [4]. For instance, epitaxial CeO$_2$ films were fabricated as the buffer layers for high temperature superconducting [5]. Furthermore, cerium oxide thin films utilized as high-$k$ dielectric material in capacitors. In addition, CeO$_2$-based electrodes were developed for solid oxide fuel cells [6] and rare earth was also found to improve optical and photoconductivity properties of Cds [7]. In addition, CeO$_2$ nanoparticles were utilized as antioxidant agents [8]. Owing to the distinctive redox properties and high oxygen storage capacity, CeO$_2$ is widely used as catalysts [9,10]. It is reported that CeO$_2$ with the cubic fluorite structure possesses a wide band gap energy of 3.2 eV which limits its photocatalytic activity under the ultraviolet (UV) radiation [11]. It is suggested that the transition metal doped CeO$_2$ nanoparticles enhance the UV absorption properties [12]. Yue et al. [13] stated that introducing some impurities (dopants) ions such as Ti, Mn , Fe and Co within the CeO$_2$ lattice enhances its photocatalytic properties and promotes the narrowing of the band gap to the visible photocatalytic characteristics leading to a significant absorption shifts towards the visible region. Truffault et al. [14] synthesized Calcium(Ca)-doped CeO$_2$ nanoparticles with doping concentrations between 0 and 50 mol% for the short ultraviolet type A radiation filtration application. Channei et al. [15] proposed that Fe-doped CeO$_2$ films exhibit superior photocatalytic performances compared to the pure CeO$_2$ films due to decreasing in band gap energy and increasing the specific surface area. Furthermore,
hydrothermal synthesis approach has been used to prepare Yttrium (Y)-doped CeO$_2$ nanorods for the degradation of indigo carmine dyes [16]. Results indicated that the photocatalytic activity increased by increasing the doping content of Y until reaching a specific doping level and additional increasing in the doping contents may result in decreasing the photocatalytic activity. The greatest improvement in photocatalytic activity is ascribed to the creation of oxygen vacancy into CeO$_2$ up to a certain limit of Y loading. However, increasing the optimum doping level showed reducing in photocatalytic activity. In another study, the effect of Samarium (Sm) doping on the structural, surface morphological, and optical properties of CeO$_2$ nanoparticles has been investigated [17]. They indicated that controlled band gap, size, grain morphology, extrinsic and intrinsic oxygen vacancies in the Sm-doping CeO$_2$ lattice promote these nanoparticles to be appropriate replacements for various applications. Further, it has been reported that doping with transition metal such as Fe, Co, and Ni was implemented to create oxygen vacancies in CeO$_2$ and enhanced activity for carbonyl sulfide hydrolysis. The strong interaction between doped metals and CeO$_2$ encourages the spontaneous generation of asymmetric oxygen vacancies in metal doped CeO$_2$ nanorods. These asymmetric oxygen vacancies would assist the activation and dissociation of H$_2$O and generation of active hydroxyls, contributing to improve the activity for COS hydrolysis [18]. Moreover, the effect of various loadings of Cu ions into the CeO$_2$ lattice is proven to enhance the optical and visible photocatalytic properties of CeO$_2$. In addition, the visible photocatalytic degradation of methylene blue in the presence of 7 wt% Cu-doped CeO$_2$ nanoparticles revealed the degradation rates about 1.41 $\times$ 10$^2$ min$^{-1}$ and 1.12 $\times$ 10$^2$ min$^{-1}$ under the exposure to natural sunlight and visible light, correspondingly [19].

From theoretical view point, a research group examined the enhancement in visible light photocatalytic performance of transition metals (Fe, Cr and Co)-doped CeO$_2$ nanomaterials. It was demonstrated that the reduced band gap and strong absorption induced by impurity levels are responsible for the enhanced visible-light photocatalytic activity of doped CeO$_2$ [20]. Moreover, density functional theory (DFT) demonstrated a powerful tool to explore the adsorption of SO$_2$ molecules over Ir/P-modified graphitic carbon nitride (gCN) to present pertinent systems that operate in sensing and eliminating SO$_2$ molecules from atmosphere. The findings of PDOS plots revealed that the sharp peak is localized near the Fermi energy level in SO$_2$-adsorbed Ir/P-modified gCN system, which confirmed the strong adsorption of SO$_2$ molecules on the studied system [21]. Another DFT study predicted that the band gap energy of graphitic carbon nitride (g-C$_3$N$_4$) decreased significantly by metal insertion of Ni, Pd and Pt [22].

First-principle calculations also implemented to inspect the effect of Hf and Zr loadings on the reduction enthalpies of CeO$_2$ configurations. In an agreement with XRD measurements, alloying these metals to the stoichiometric and reduced CeO$_2$ lattice correlates with the reduction in their volume cells. Furthermore, reduces their reduction enthalpy, and hence displaying an enhancement in the catalytic activities of Hf/Zr-CeO$_2$ systems [23].

To this end, this computational work aims to investigate the effect of transition metal of Ti on the photocatalytic and optical characteristics of CeO$_2$. Furthermore, Mulliken population analysis is considered to compute the charge transfer for the individual atoms in molecules of the systems, and thereafter, exploring the bonding character between the constituents in the molecules. In this study, Ti as a dopant was selected owing to its smaller ionic radius than Ce and easily replacing in Ce lattice.

**METHOD OF CALCULATIONS**

The calculations were achieved with the Cambridge serial total energy package (CASTEP) code, based on the density functional theory [24]. Owing to the strong Coulomb interaction of the localized Ce 4f electrons, the standard density functional theory (DFT) calculations underestimate the band gap [25]. Hence, density functional correlated (GGA + U) calculations were applied in this study. Moreover, based on the default setting of CASTEP software, the value of the utilized Hubbard parameter (U) corresponds to 6.0 eV and 2.5 eV for Ce and Ti, respectively. Electron-ion interactions were described through ultrasoft pseudopotentials in reciprocal space with valence electron configurations of 2s$^2$ 2p$^6$ for oxygen, 3d$^4$ 4s$^2$ for titanium atom and 4f$^2$ 5s$^2$ 5p$^6$ 6d$^1$ 6s$^2$ for cerium. Initially, the calculations were performed at a supercell of

2×1×1 comprised of 8-cerium atoms and 16 oxygen atoms. To set the Ti-doped models, the substitutional method was implemented at \( x = 0.125, 0.250, 0.500, 0.750 \) and 0.875. Suggesting that at \( x = 0.125 \), only one Ce atom has been substituted by Ti, at \( x = 0.250 \), two Ce atoms are substituted, at \( x = 0.500 \) four Ce atoms are replaced, at \( x = 0.750 \) six Ce atoms are replaced, and at \( x = 0.875 \) seven Ce atoms are replaced by Ti.

In a similar manner, the \( \text{Ce}_{1-x}\text{Ti}_x\text{O}_2 \) system corresponds to Ce concentration of \( x = 0.125, 0.25, 0.500, 0.750, 0.875 \) as disclosed in Fig. 1. The total energy was minimized for \( \text{CeO}_2 \) using a set of k-points in the irreducible sector of Brillouin zone, equivalent to a \( 3\times2\times2 \) Monkhorst-Pack grid in the unit cells, and a cutoff energy of 300 eV. The convergence tolerance of energy was set at \( 5.0 \times 10^{-6} \) eV/atom. Regarding the optimization process, the energy change, maximum force, maximum stress, and maximum displacement tolerances were set as \( 1 \times 10^{-6} \) eV/atom, 0.03 eV/Å, 0.05 GPa, and 0.001 Å, correspondingly. Finally, the scissor operator of 0.98 eV was applied to reproduce the measured electronic band gap [26, 27]. This value of scissors operator was implemented to all the subsequent optical calculation.

**RESULTS AND DISCUSSION**

**Geometry Optimization of Pure and Ti-doped CeO\(_2\)**

The optimized supercells of pure and Ti-doped \( \text{CeO}_2 \) are shown in Fig. 1. It is well known that \( \text{CeO}_2 \) displays a cubic fluorite lattice with the space group of Fm-3m which is composed of four formula units in a unit cell (i.e., 4 cerium and 8 oxygen atoms). Our simulated findings of the lattice parameters are in accordance with that of the experimentally measured value of \( a = 5.410 \) Å. These results correspond well with those in the previously published work [28].

The lattice parameters and Mulliken population results of the optimized configurations are reported in Table 1. The lattice parameters values of the optimized configurations decreased with the increasing Ti-doping concentration. This is ascribed to a noticeable lattice distortion while introducing Ti ions.

Table 1 lists Mulliken charges on Ce, O and Ti atoms in \( \text{Ce}_{1-x}\text{Ti}_x\text{O}_2 \) system. From the table, it is observed that Ce and Ti atoms in the simulated structures hold positive charges while O atoms are associated with negative charges. Our
analysis of Mulliken charge values indicates a covalent character for Ti-Ce bond in all the simulated systems that have Ti and Ce atoms and ionic characteristics for Ti-O and Ce-O bonds. Moreover, these results demonstrate that Ce atoms lose more electrons when introducing Ti into the system, whereas the electron gains of O atoms are almost steady when Ti contents increased [29].

**Density of States (DOSs) Analysis**

To investigate the electronic properties of Ce$_{1-x}$Ti$_x$O$_2$ system, the electronic density of states (DOSs) of the optimized supercells is demonstrated in Fig. 2. Our findings show that the CeO$_2$ structure displays a nonmetallic nature, which indicates a semiconducting character. The Fermi level is located at zero energy to easily recognize the band gap. For $x = 0$ (pure CeO$_2$ configuration), DOS of CeO$_2$ agreed well with the previous literature [30]. The topmost valance band is stretching from -4.0 to 0 eV (Fermi level) and the conduction band is positioned at 3.19 eV above the Fermi level, suggesting that the estimated band gap has reproduced the experimental value of 3.19 [31] as depicted in Fig. 2a. Introducing Ti contents (0.125, 0.25, 0.500, 0.750 and 0.875) into the system would increase the intensity of states in the conduction and valence bands. However, the electronic band gap is reduced to 2.88, 2.67, 2.33, 2.28 and 2.19 eV at Ti loadings of 0.125, 0.25, 0.500, 0.750 and 0.875, respectively. This result indicates that Ti incorporation into ceria would induce an obvious band gap narrowing.

An investigation of Ti 3$d$ orbital of each configuration was performed and the results are displayed in Fig. 3. The Ti 3$d$ states in Ce$_{1-x}$Ti$_x$O$_2$ ($x = 0.125$, 0.250, 0.500, 0.750 and 0.875) systems are located at about similar energy range, suggesting that the Ti 3$d$ states enhance gradually with increasing Ti concentrations. Moreover, the decrease in the band gap caused by the Ti incorporation is mainly due to increasing the Ti 3$d$ states in the conduction band which is the core reason for enhancing the photocatalytic and optical activities of Ti-doped CeO$_2$.

For further understanding the contribution of each of

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**Table 1. The Calculated Lattice Constants (Å), Formation Energy for the Studied Systems (eV), Band Gap (eV) and Charge Transfer (e) for Pure and Ti-doped CeO$_2$ Configurations**

<table>
<thead>
<tr>
<th>Configuration</th>
<th>Lattice constants (Å)</th>
<th>Formation energy (eV)</th>
<th>Band gap (eV)</th>
<th>Charge transfer (e)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td></td>
<td></td>
<td></td>
<td>Ce</td>
</tr>
<tr>
<td>CeO$_2$</td>
<td>$a = 5.41$</td>
<td>$-1.94 \times 10^3$</td>
<td>3.19</td>
<td>1.27</td>
</tr>
<tr>
<td>Ce$_{1-x}$Ti$_x$O$_2$, $x = 0.125$</td>
<td>$a = 5.39$</td>
<td>$-1.60 \times 10^4$</td>
<td>2.88</td>
<td>1.33</td>
</tr>
<tr>
<td>Ce$_{1-x}$Ti$_x$O$_2$, $x = 0.250$</td>
<td>$a = 5.35$</td>
<td>$-1.66 \times 10^4$</td>
<td>2.67</td>
<td>1.36</td>
</tr>
<tr>
<td></td>
<td>$a = 5.18$</td>
<td></td>
<td></td>
<td>1.37</td>
</tr>
<tr>
<td>Ce$_{1-x}$Ti$_x$O$_2$, $x = 0.500$</td>
<td>$a = 5.04$</td>
<td>$-1.87 \times 10^4$</td>
<td>2.28</td>
<td>1.56</td>
</tr>
<tr>
<td></td>
<td>$a = 4.91$</td>
<td>$-1.93 \times 10^4$</td>
<td>2.19</td>
<td>1.57</td>
</tr>
</tbody>
</table>
the related orbitals to the partial density of states (PDOS), analysis of 5d and 4f orbitals of each configuration was performed and the results are depicted in Fig. 4. At x = 0 (pure CeO₂), 4f orbitals of Ce atoms are predominant in the conduction band. However, the valence band is found to be mixed with both 4f and 5d orbitals.

**Analysis of Optical Properties**

It is well known that the strong light absorption is an indication of a high efficiency photocatalyst. The computed
absorption coefficients of pure and Ti-modified CeO$_2$ configurations as a function of wavelength in the range of 200-1500 nm is depicted in Fig. 5. It is evident from the figure that pure CeO$_2$ spectrum shows a good absorption character for the incident photons in the ultra-violet part of the solar irradiation, whereas a slight component in the visible region is presented. However, the absorption edge shifted towards the visible light region when inserting Ti. This may be attributed to the incorporation of transition metals into the ceria lattice resulted in the formation of new

![Graphs showing 3d orbitals of Ti ion loadings at different concentrations](image)

*Fig. 3. 3d orbitals of Ti ion loadings at (a) x = 0.125, (b) x = 0.250, (c) x = 0.500, (d) x = 0.750 and (e) x = 0.875.*
energy levels in the conduction band (Ti-3d) as demonstrated in Fig. 3. This in turn causes a red shift for the spectra, improving the photocatalytic performance of the studied systems. Furthermore, pure CeO₂ shows a good transparency in the visible range nominating this material for the optical applications. Furthermore, Ti-doped CeO₂ adsorption curves display relatively a comparable absorption values showing a good performance in the solar
It is well known that less reflectivity of a material exhibits high performance in solar cell applications [32].

Reflectivity spectra for the considered systems are displayed in Fig. 6. The spectra demonstrate minimal values for the Ti-modified CeO₂ systems in the visible range of the spectrum.
Photocatalytic and Optical Performances


Electromagnetic waves (EM). This reduction in reflectivity is extended to some UV reign, reflecting good characters for such materials. The DFT computed absorption and reflectivity spectra of pure CeO$_2$ exhibit a similar trend with our previous experimental work [32] in the wavelength range between 200 and 1500 nm. Both theoretical and measured results have peaks in shorter wavelengths.

The dielectric function corresponds to the interaction between the incident photons and electrons in a material. Optical transitions between occupied and unoccupied states are caused by the electric field of the photon. The spectra from the excited states can be identified as a joint density of

Fig. 7. The real and imaginary parts of dielectric function of Ce$_{1-x}$Ti$_x$O$_2$ at (a) $x = 0$, (b) $x = 0.125$, (c) $x = 0.25$, (d) $x = 0.500$, (e) $x = 0.750$, and (f) $x = 0.875$. 
states between the valence and conduction bands [26]. The dielectric functions involve two effects which are inraband effects from the contribution of free electrons and interband effects from the contribution of valence electrons [33]. The imaginary part of the dielectric function \( \varepsilon_2(\omega) \) can be computed from the momentum matrix elements between the occupied and unoccupied wave functions [27]. The real part \( \varepsilon_2(\omega) \) of the dielectric function can be assessed from the imaginary part \( \varepsilon_2(\omega) \) by Kramer-Kronig transformation [34]. The wavelength dependent spectra of the real and imaginary parts of the complex dielectric function of pure and doped CeO\(_2\) are depicted in Fig. 7. The obvious zero values of \( \varepsilon_2(\omega) \) at wavelengths longer than 650 nm demonstrate a high-quality transparent material for optical applications [32].

CONCLUSIONS

This is a report of a first-principle study to evaluate the effect of Ti-insertion on the electronic and optical properties of CeO\(_2\). The obtained results suggested that the Ti incorporation into ceria could evidently induce band gap narrowing to 2.88, 2.67, 2.33, 2.28 and 2.19 eV at Ti contents of 0.125, 0.25, 0.500, 0.750 and 0.875 correspondingly. Furthermore, Ti-doping introduces 3d states in the conduction band of CeO\(_2\). The 3d states play an important role on reducing the band gap. Moreover, the optical absorption shifts to a longer wavelength range indicating the possible applications as a photocatalytic material. Analysis of Mulliken charges suggests an ionic character for Ce-O and Ti-O bonds, while a covalent character was found for the Ce-Ti bond.

REFERENCES


[12] Dao, N. N.; Luu, M.; Dai, Nguyen, Q. K.; Kim, B. S.,


[28] Xue, Y.; Tian, Y.; Zhang, D.; Zeng, C.; Fu, Y.; Li, K.; Wang, H.; Tian, Y., The mechanism of photocatalyst and the effects of co-doping CeO2 on...


